S4D065V015A

SiC Schottky Diode

Features:

- 650V Schottky Diode
- Zero Reverse Recovery Current
- High Frequency Operation
- Positive Temperature Coefficient
- Temperature independent Switching

Benefits:

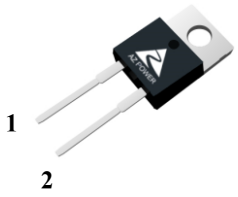
- Unipolar Rectifier
- Minimal switching loss
- Higher Efficiency
- Low cooling requirement

Symbol	Value	Unit
V_{RRM}	650	V
$I_{F\ (Tc=146^oC)}$	15	A
Q_C	34	nC

Applications:

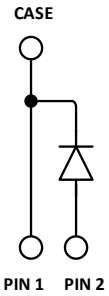
- Switch Mode Power Supply
- Booster diodes in PFC, DC/DC
- AC/DC converters

Outline



TO-220-2L

Circuit



Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions
V_R	DC Peak Reverse Voltage	650	V	T_J =25°C
V_{RRM}	Repetitive Peak Reverse	650	V	T_J =25°C
V_{RSM}	Surge Peak Reverse Voltage	650	V	T_J =25°C
I_F	Continuous Forward Current	42 19 15	A	T_C =25°C T_C =135°C T_C =146°C
I_{FRM}	Repetitive Peak Forward Surge Current	91 81	A	T_C =25°C, T_P=10ms, Half Sine Wave Tc=110°C, T_P =10ms, Half Sine Wave
I_{FSM}	Non-Repetitive Peak Forward Surge Current	120 109	A	T_C =25°C, T_P =10ms, Half Sine Wave Tc=110°C, T_P =10ms, Half Sine Wave
P_D	Power Dissipation	150 50	W	T_C =25°C Tc=125°C
$T_{J,max}$	Operating Junction Temperature	175	°C	
T_{stg}	Storage Temperature Range	-55 to 175	°C	

Thermal characteristics

Symbol	Parameter	Min.	Typ.	Max.	Unit
R_{thJC}	Thermal resistance		1.0		°C/W

Electrical Characteristics

Symbol	Parameter	Value			Unit	Test Conditions
		Min.	Typ.	Max.		
V_{DC}	DC Blocking Voltage	650			V	I_R = 100μA, T_J = 25°C
V_F	Forward Voltage		1.45 1.8	1.7 2.1	V	I_F = 15A, T_J = 25°C I_F = 15A, T_J = 175°C
I_R	Reverse Current		5 10	100 200	μA	V_R = 650V, T_J = 25°C V_R = 650V, T_J = 175°C
Q_C	Total Capacitive Charge		34		nC	I_F = 15A, dI/dt = 350A/μs T_J = 25°C, V_R = 400V
C	Total Capacitance		644 88 85		pF	V_R = 1V, T_J = 25°C, f = 1 MHz V_R = 200V, T_J = 25°C, f = 1 MHz V_R = 400V, T_J = 25°C, f = 1 MHz

Typical Performance

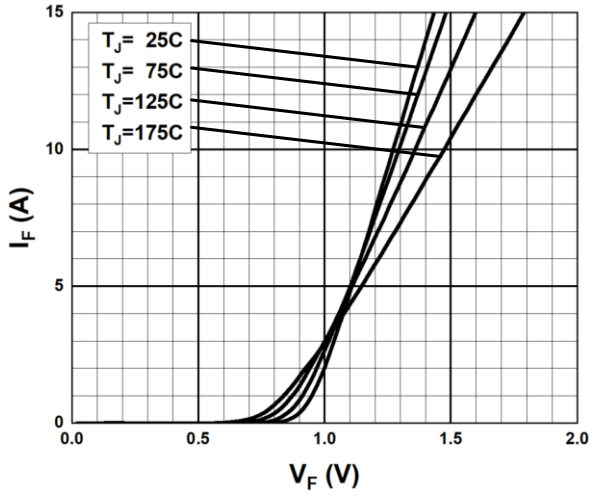


Fig. 1 Forward Characteristics

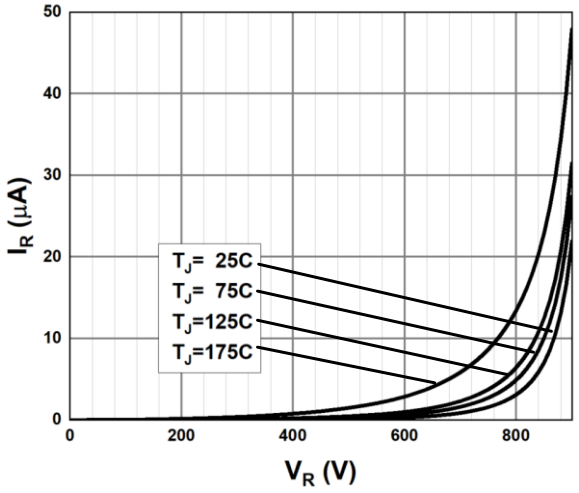


Fig. 2 Reverse Characteristics

Typical Performance

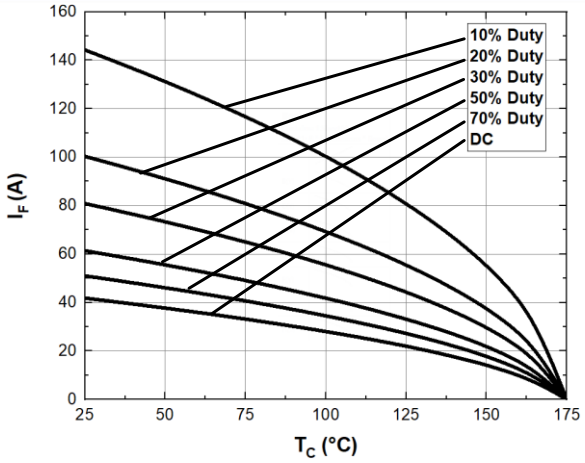


Fig. 3 Current Derating

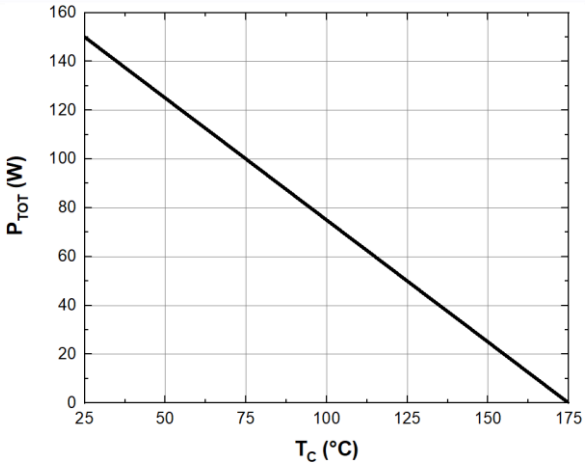


Fig. 4 Power Derating

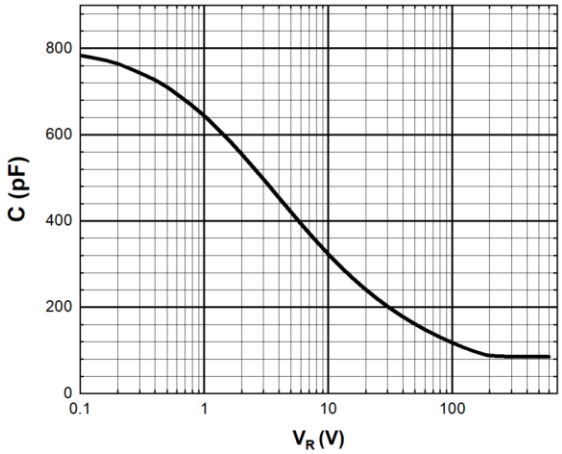


Fig. 5 Capacitance vs. Reverse Voltage

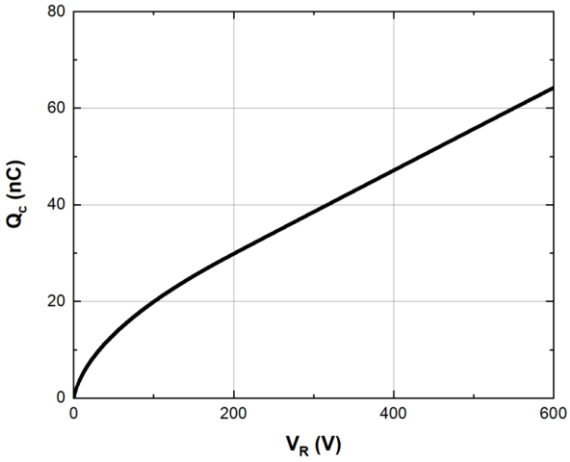


Fig. 6 Recovery Charge vs. Reverse Voltage

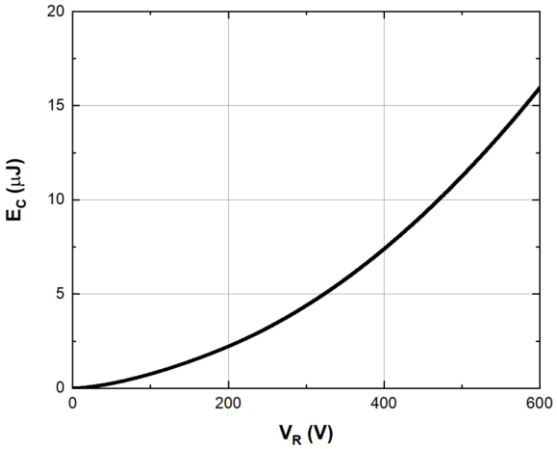


Fig. 7 Capacitance stored Energy

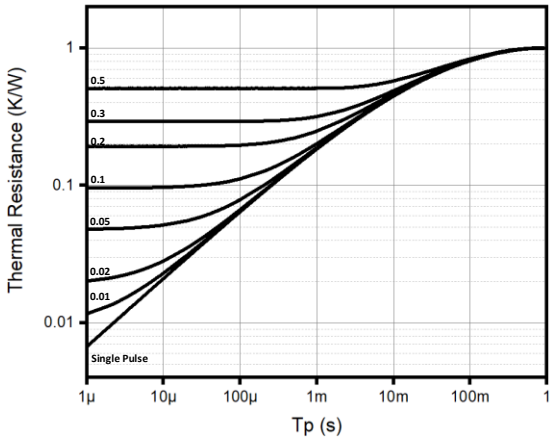
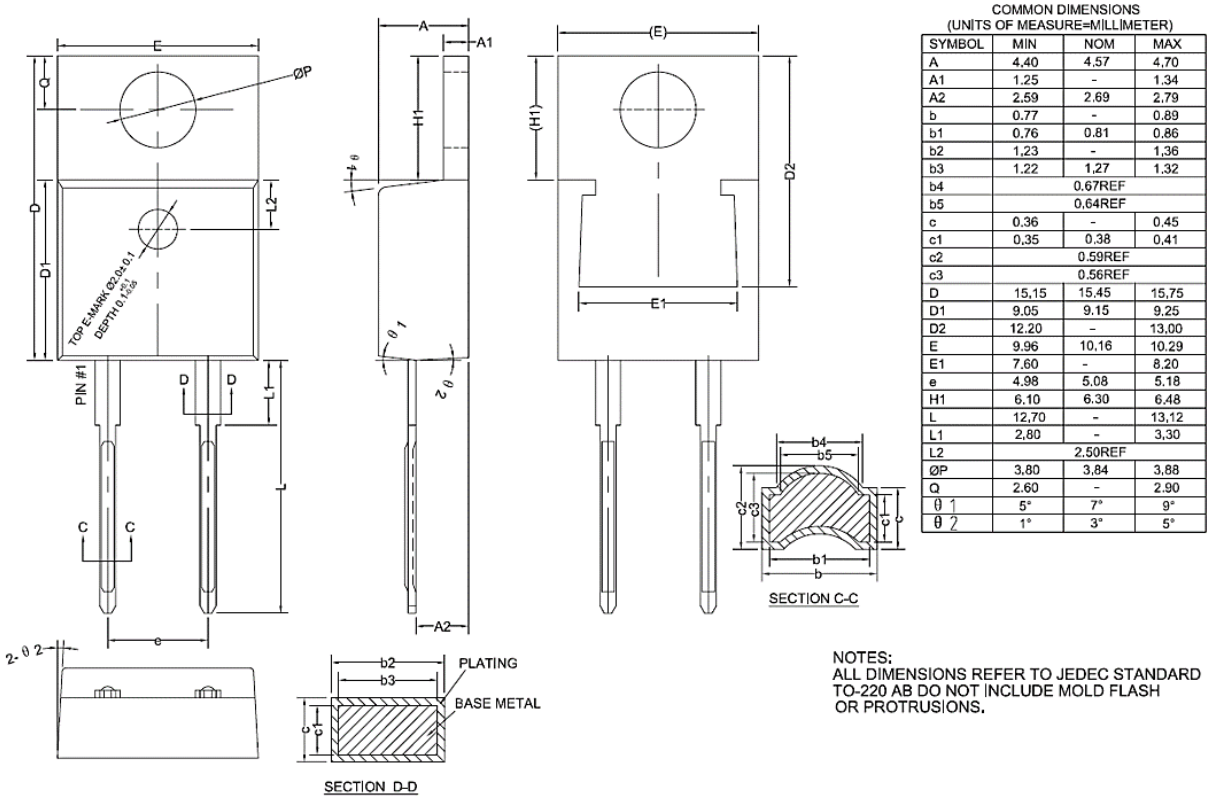


Fig. 8 Transient Thermal Impedance

Package TO-220-2L （Unit: mm）



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	4.40	4.57	4.70
A1	1.25	-	1.34
A2	2.59	2.69	2.79
b	0.77	-	0.89
b1	0.76	0.81	0.86
b2	1.23	-	1.36
b3	1.22	1.27	1.32
b4		0.67REF	
b5		0.64REF	
c	0.36	-	0.45
c1	0.35	0.38	0.41
c2		0.59REF	
c3		0.56REF	
D	15.15	15.45	15.75
D1	9.05	9.15	9.25
D2	12.20	-	13.00
E	9.96	10.16	10.29
E1	7.60	-	8.20
e	4.98	5.08	5.18
H1	6.10	6.30	6.48
L	12.70	-	13.12
L1	2.80	-	3.30
L2		2.50REF	
ØP	3.80	3.84	3.88
Q	2.60	-	2.90
θ1	5°	7°	9°
θ2	1°	3°	5°

NOTES:
ALL DIMENSIONS REFER TO JEDEC STANDARD TO-220 AB DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.

This Product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, systems, or air-traffic control systems.

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